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## MAIN REQUEST

## CLAIMS

- 1. Apparatus for selectively interfering with pathological cells survival processes in vitro and in vivo comprising:
- means for generating static magnetic (S) fields crossing a working environment,
- means for gamerating electromagnetic extremely low frequency (ELF) fields over said working environment in addition to said S fields;

characterised in that it further comprises:

- means for modulating said S fields associated to said means for generating S fields, said means for modulating said S fields setting the intensity of said S fields between 1 and 100 mT according to a predetermined function of intensity versus time;
  - means for modulating said ELF fields associated to said means for generating ELF fields, said means for modulating said ELF fields setting said ELF fields according to a predetermined function of amplitude of intensity between 1 and 100 mT and frequency between 1 and 1000 Hz versus time.
  - 2. Apparatus for selectively interfering with pathological cells survival processes in vitro and in vivo comprising:
  - means for generating static magnetic (S) fields crossing a working environment,

characterised in that it further comprises

- means for modulating said S fields associated to said generating means, said means for modulating the S fields setting the intensity of said S fields between 1 and 100 mT according to a predetermined function of intensity versus time.

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- 3. Apparatus for selectively interfering with pathological cells survival processes in vitro and in vivo characterised in that it further comprises
- means for generating electromagnetic extremely low frequency (ELF) fields over said working environment;
- means for modulating said ELF fields associated to said means for generating said means for modulating said ELF fields according to a predetermined function of amplitude of intensity between 1 and 100 mT and frequency between 1 and 1000 Hz versus time.
- 4. Apparatus according to any of claims 1 or 2 wherein said means for modulating said S fields comprises program means that set said intensity following a plurality of predetermined step values Is1, Is2, ..., Isn for corresponding time intervals T1, T2, ..., Tn
- 5. Apparatus according to any of claims 1 or 3 wherein said means for modulating said ELF fields comprises program means that set said intensity amplitude following a plurality of predetermined step values Inter, Islam, ..., IELEM for corresponding time intervals T1, T2, ..., Ta.
- 6. Apparatus according to any of claims 1 or 3 wherein said means for modulating said ELF fields comprises program means that set said frequency following a plurality of predetermined step values f<sub>1</sub>, f<sub>2</sub>,..., f<sub>n</sub>, for corresponding time intervals T<sub>1</sub>, T<sub>2</sub>, ..., T<sub>n</sub>, said step values being comprised between 10 and 100 Hz.
- 7. Apparatus according to claim 1, wherein said means for modulating said S and ELF fields comprises program means that set an S/ELF ratio according to a plurality of predetermined step values Isi/Impt, Isi/Impt, Isn/Impt, for corresponding time intervals T1, T2, ..., Ta,.
- 8. Apparatus according to claim 7, wherein said program

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means set said S and ELF fields according to an overall intensity between 1 and 30 mT and respectively a ratio S/ELF comprised between 0,1 and 10.

- 9. Apparatus according to claim 7, wherein said program
  5 means set said S and ELF fields according to an overall
  intensity between 1 and 10 mT and respectively a ratio
  S/ELF comprised between 0,5 and 5.
  - 10. Apparatus according to claims 4 to 9 wherein said program means set said time intervals between 1 and 40 minutes.
  - 11. Apparatus according to the previous claims wherein at least a portion of said working environment is defined by walls permeable to said fields.
  - 12. Apparatus according to the previous claims, wherein said means for generating said S and/or ELF fields a second and first least a \ comprise at respectively surrounding at least a portion of said environment, said means for modulating AC DC and/or said coils providing to respectively.
  - 13. Apparatus according to the claims from 1 to 11, wherein said means for generating said S and/or ELF fields comprise at least a first and a second coil coaxial to each other, said working environment being placed between said first and a second coil and said means for modulating providing to said coils DC and/or AC current respectively.
  - 16. Apparatus according to the previous claims, wherein means are provided for creating through said working environment a static electric field or a low frequency variable electric field up to 1000 Hz, having intensity up to 20 kV/m.
  - 15. The use of SELF non thermal field for selectively

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in particular cells affected by cancer, viral infections, autoimmune diseases, neurodegenerative disorders, AIDS, etc., characterised in that said SELF non thermal fields have intensity comprised between 1 and 100 mT, said SELF fields being different sequences of S and/or ELF fields, i.e. S fields followed by ELF fields, ELF fields followed by S fields, S and ELF field together, as well as the presence of S or ELF fields alone, said ELF fields having a field frequency comprised between 1 and 1000 Hz.

- fields for non thermal SELF' of use 16. The genes \ modifications, such biotechnological particular for modification of mutant p53 characterised in that said SELF non thermal fields have intensity comprised between 1 and 100 mT, said SELF fields being different sequences of S and/or fields, i.e. S fields followed by ELF fields, ELF fields followed by S fields, \S and ELF field together, as well as the presence of S or ELF fields alone, said ELF fields having a field frequency comprised between 1 and 1000 Hz.
- 17. The use of SELF non thermal fields according to claims
  15 or 16, wherein chemical substances are used in
  addition to the SELF fields.
- 18. The use of SELF non thermal fields according to claims 15 or 16, wherein said different sequences of S and/or ELF fields sequences are set for time intervals T<sub>1</sub>, T<sub>2</sub>, ..., T<sub>n</sub>, and wherein in said time intervals the intensity of said S and/or ELF fields are set at steady values Is<sub>1</sub>, I<sub>S2</sub>, ..., I<sub>en</sub>; I<sub>ELF1</sub>, I<sub>ELF2</sub>, ..., I<sub>ELF2</sub>, I<sub>S1</sub>/I<sub>ELF2</sub>, I<sub>S1</sub>/I<sub>ELF2</sub>, ..., I<sub>ELF2</sub>, ...,
- 19. The use of SELF non thermal fields according to claims

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15 or 16, wherein said S and ELF fields are set at an overall intensity between 1 and 30 mT with respectively a ratio S/ELF comprised between 0.1 and 10.

20. The use of SELF non thermal fields according to claims 15 or 16, wherein said S and ELF fields are set at an overall intensity between 1 and 10 mT with respectively a ratio S/ELF comprised between 0,5 and 2,5.